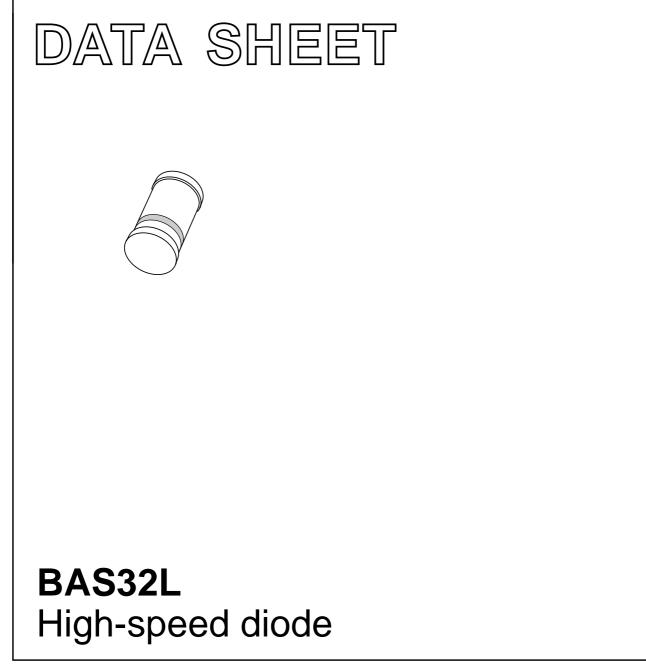
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1996 Sep 10 2002 Jan 23



Product specification

BAS32L

FEATURES

- Small hermetically sealed glass
 SMD package
- High switching speed: max. 4 ns
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 100 V
- Repetitive peak forward current: max. 450 mA.

APPLICATIONS

- High-speed switching
- Fast logic applications.

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

DESCRIPTION

package.

The BAS32L is a high-speed switching diode fabricated in planar technology,

and encapsulated in the small hermetically sealed glass SOD80C SMD

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Fig.1 Simplified outline (SOD80C) and symbol.

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SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{RRM}	repetitive peak reverse voltage		-	100	V
V _R	continuous reverse voltage		_	75	V
I _F	continuous forward current	see Fig.2; note 1	-	200	mA
I _{FRM}	repetitive peak forward current		_	450	mA
I _{FSM}	non-repetitive peak forward current	square wave; T _j = 25 °C prior to surge; see Fig.4			
		t = 1 μs	-	4	A
		t = 1 ms	-	1	A
		t = 1 s	-	0.5	A
P _{tot}	total power dissipation	T _{amb} = 25 °C; note 1	-	500	mW
T _{stg}	storage temperature		-65	+200	°C
Tj	junction temperature		-	200	°C

The marking band indicates the cathode.

Note

1. Device mounted on an FR4 printed-circuit board.

BAS32L

ELECTRICAL CHARACTERISTICS

$T_i = 25 \ ^{\circ}C$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _F	forward voltage	see Fig.3			
		$I_F = 5 \text{ mA}$	620	750	mV
		I _F = 100 mA	-	1000	mV
		I _F = 100 mA; T _j = 100 °C	-	930	mV
I _R	reverse current	see Fig.5			
		V _R = 20 V	-	25	nA
		V _R = 75 V	-	5	μA
		$V_R = 20 \text{ V}; \text{ T}_j = 150 ^{\circ}\text{C}$	-	50	μA
		V _R = 75 V; T _j = 150 °C	-	100	μA
V _{(BR)R}	reverse breakdown voltage	I _R = 100 μA	100	-	V
C _d	diode capacitance	$f = 1 MHz; V_R = 0; see Fig.6$		2	pF
t _{rr}	reverse recovery time	when switched from $I_F = 10$ mA to $I_R = 10$ mA; $R_L = 100 \Omega$; measured at $I_R = 1$ mA; see Fig.7		4	ns
V _{fr}	forward recovery voltage	when switched from $I_F = 50$ mA; $t_r = 20$ ns; see Fig.8	_	2.5	V

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-tp}	thermal resistance from junction to tie-point		300	K/W
R _{th j-a}	thermal resistance from junction to ambient	note 1	350	K/W

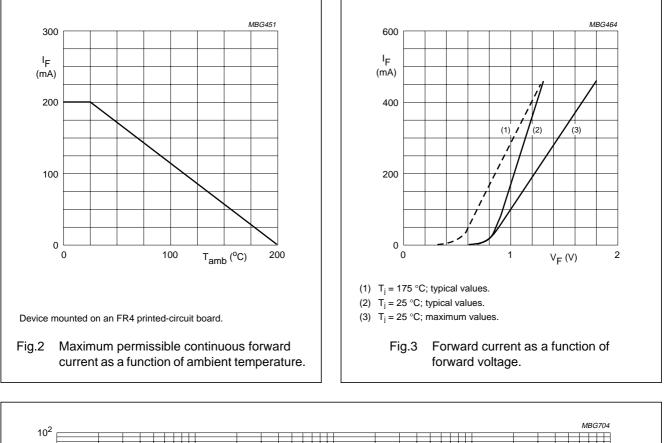
Note

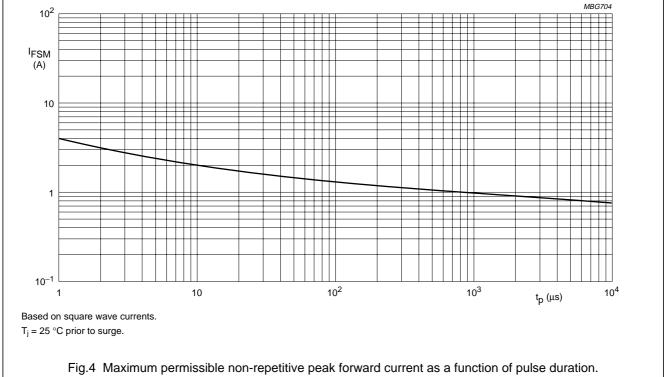
1. Device mounted on an FR4 printed-circuit board.

Product specification

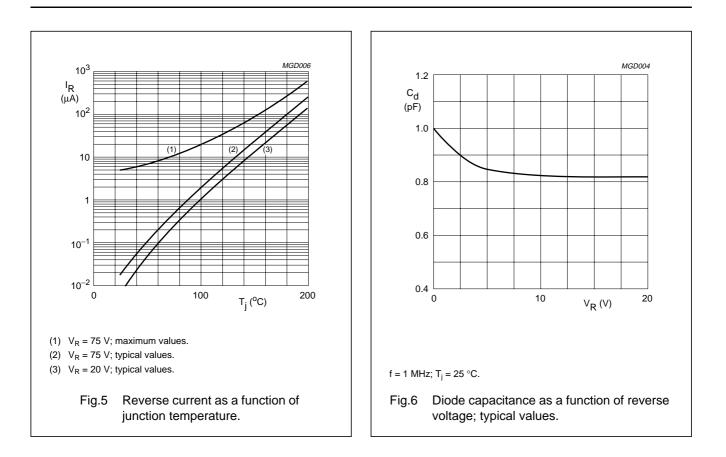
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GRAPHICAL DATA

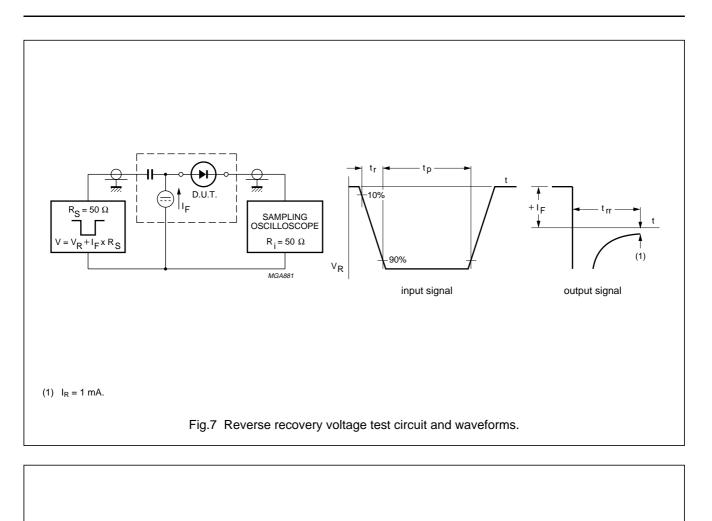


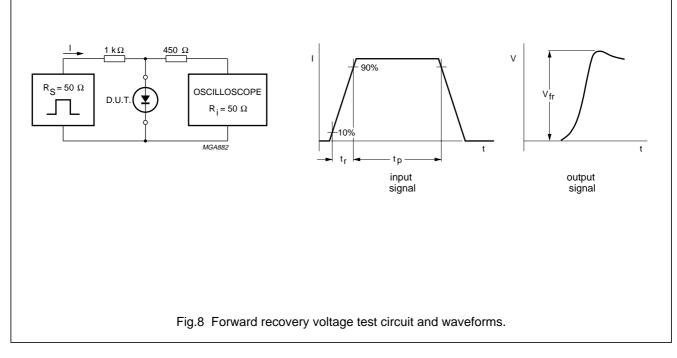


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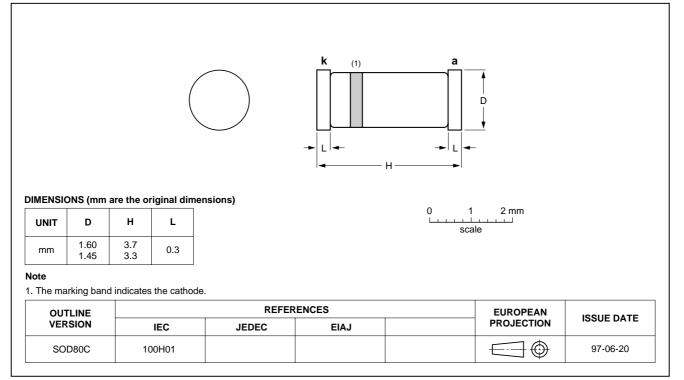
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PACKAGE OUTLINE

Hermetically sealed glass surface mounted package; 2 connectors



BAS32L

SOD80C

Product specification

High-speed diode

BAS32L

DATA SHEET STATUS

DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Notes

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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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